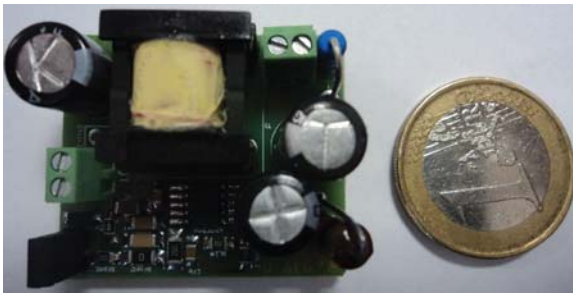
STEVAL-ISA113V1

Wide range single-output demonstration board based on the VIPER06HS

Data brief

Features

- Universal input mains range:
  - input voltage 90 - 265 V_{AC}
  - frequency 45 - 65 Hz
- Single-output voltage: 12 V at 0.35 A continuous operation
- Standby mains consumption: < 30 mW at 230 V_{AC}
- Average efficiency: > 74%
- Fully protected against faults (overload, feedback disconnection and overheating)
- EMI: according to EN55022-Class-B
- RoHS compliant



STEVAL-ISA113V1

Description

The STEVAL-ISA113V1 demonstration board is a 12 V-0.35 A power supply set in non-isolated flyback topology using the new VIPER06HS offline high-voltage converter by STMicroelectronics.

The features of the device include an 800 V avalanche rugged power section, PWM operation at 115 kHz with frequency jittering for lower EMI, current limiting with adjustable set point, onboard soft-start, a safe auto-restart after a fault condition and a low standby power.

The protection features available include a thermal shutdown with hysteresis, delayed overload protection, and open loop failure protection.

1 Adapter features

The electrical specifications are given in *Table 1*, the schematic in *Figure 1*, and the bill of material in *Table 2*.

Table 1. Electrical specifications

Parameter	Symbol	Value
Input voltage range	V_{IN}	[90 V_{AC}; 265 V_{AC}]
Output voltage	V_{OUT}	12 V
Max. output current	I_{OUT}	0.35 A
Precision of output regulation	ΔV_{OUT_LF}	±5%
High frequency output voltage ripple	ΔV_{OUT_HF}	50 mV
Max. ambient operating temperature	T_{AMB}	60 °C

Table 2. Bill of material

Ref.	Part	Description	Package	Manufacturer
Cin1		2.2 µF, 400 V NHG series electrolytic capacitor		
Cin2		4.7 µF, 400 V AX series electrolytic capacitor		Saxon
CVDD		1 µF, 50 V electrolytic capacitor	1206	Murata
Cfilt1		100 nF, 50 V ceramic capacitor	0805	
Cfilt2	Not mounted			
Cc		10 nF, 50 V ceramic capacitor	1206	
Cp		1 nF, 50 V ceramic capacitor	1206	
Cfb		1 nF, 50 V ceramic capacitor	0805	
Cout		330 µF, 16 V ZL series ultra-low ESR electrolytic cap.		Rubycon
D0	MB6S	600 V, 1 A diode bridge	TO-269AA	Vishay
D2	STPS2H100	100 V, 2 A power Schottky rectifier	SMA	ST
Daux	1N4148W	Surface mount fast switching diode	SOD-123	Zetex
R0		4.7 Ω 3/4 W resistor		
RLIM		15 kΩ 5% 1/4 W resistor	0805	
Rc		47 kΩ 5% 1/4 W resistor	0805	
RfbH1		33 kΩ 1% 1/4 W resistor	0805	
RfbH2		0 Ω	1206	
RfbL1		12 kΩ 1% 1/4 W resistor	1206	
RfbL2		0.47 kΩ 1% 1/4 W resistor	0805	

Table 2. Bill of material (continued)

Ref.	Part	Description	Package	Manufacturer
IC1	VIPer06HS	Offline high-voltage PWM controller	SSO-10	ST
T1	1921.0040	Transformer		Magnetica
Lin	B82144A2105J	1 mH inductor LBC series		Epcos

The transformer core is a standard E13. The output voltage value is set in a simple way through the RfbH-RfbL voltage divider between the output terminal and the FB pin, according to the following formula:

Equation 1

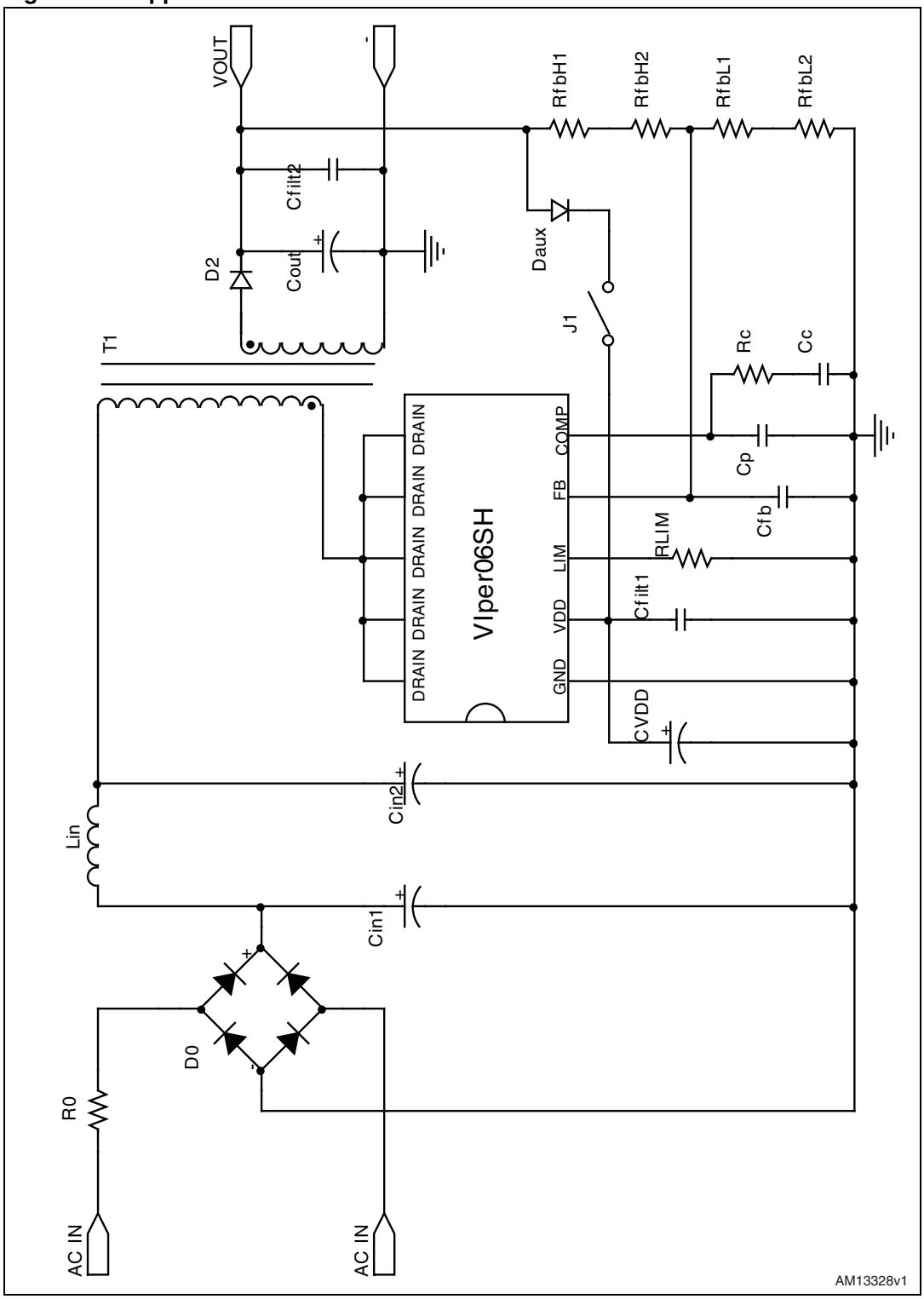
$$V_{OUT} = 3.3V \cdot \left(1 + \frac{RfbH}{RfbL}\right)$$

In the schematic, RfbH has been split into RfbH1 and RfbH2; and RfbL into RfbL1 and RfbL2 in order to allow a better tuning of the output voltage value.

If the jumper J1 is not selected, the IC is biased through the internal HV-startup current generator (“self-biasing”).

If low standby consumption and good efficiency performance are required, the HV-startup current generator must be excluded. This can be done selecting the jumper J1, which connects the output terminal to the V_{DD} pin through a small signal diode. The IC biasing through the output is referred to as “external biasing”.

Figure 1. Application schematic



2 Measurements

Figure 2. Line regulation at different loads: IC externally biased (J1 selected)

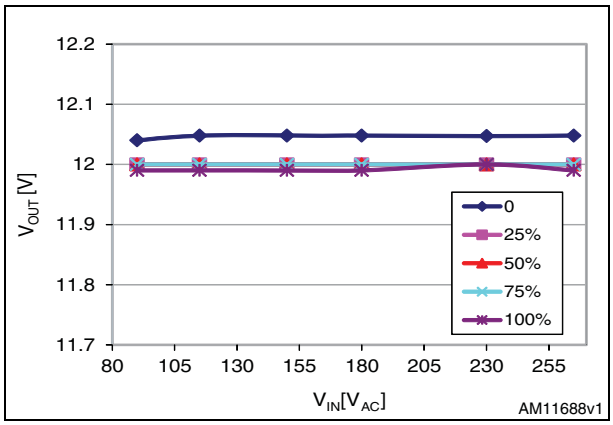


Figure 3. Line regulation at different loads: IC self-biased (J1 not selected)

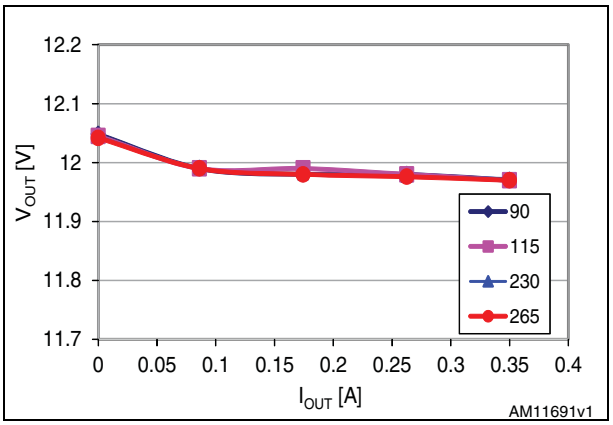


Figure 4. Efficiency vs. V_{IN} IC externally biased (J1 selected)

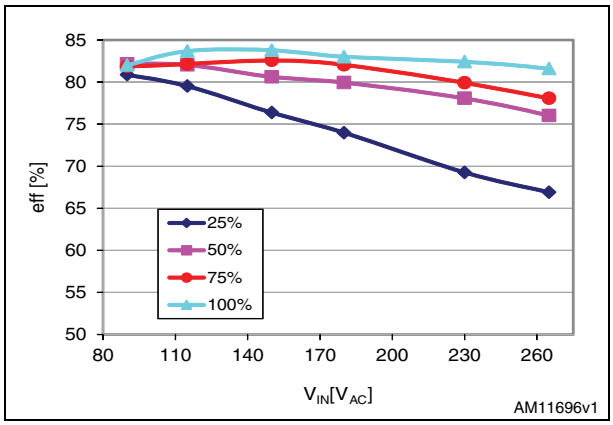


Figure 5. Efficiency vs. V_{IN} IC self-biased (J1 not selected)

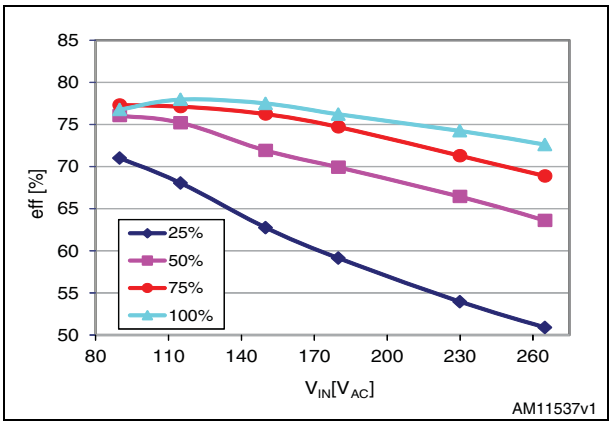


Figure 6. Efficiency at different input voltages: IC externally biased (J1 selected)

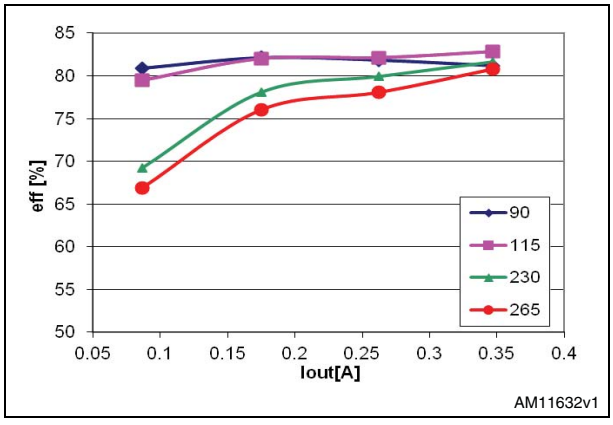


Figure 7. Efficiency at different input voltages: IC self-biased (J1 not selected)

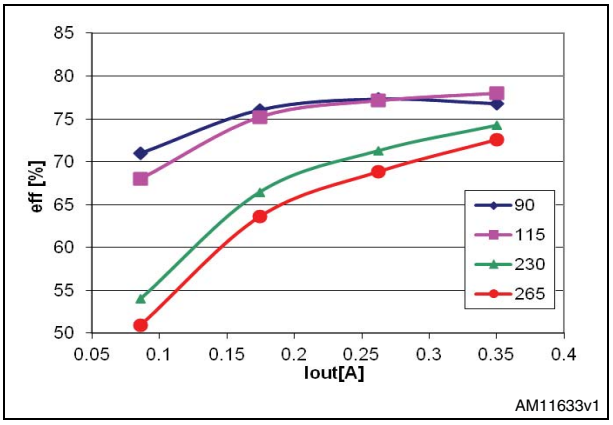


Figure 8. Active mode efficiency vs. V_{IN} IC externally biased (J1selected)

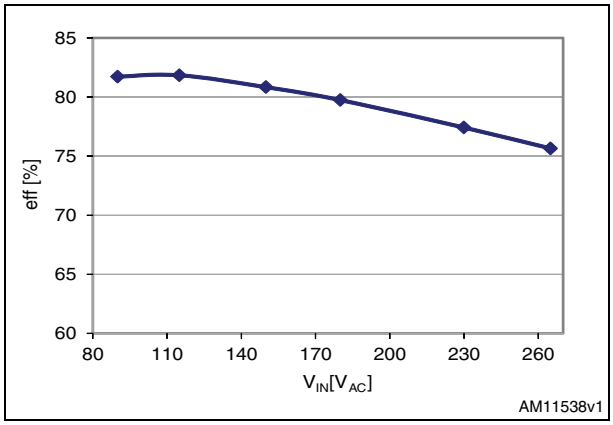


Figure 9. Active mode efficiency vs. V_{IN} IC self-biased (J1 not selected)

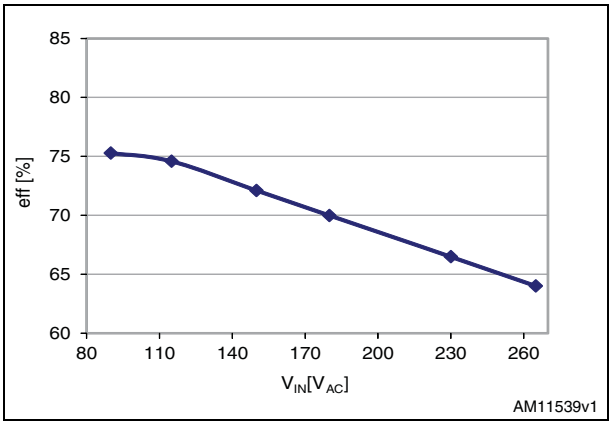


Figure 10. Input voltage averaged efficiency vs. load IC externally biased (J1 selected)

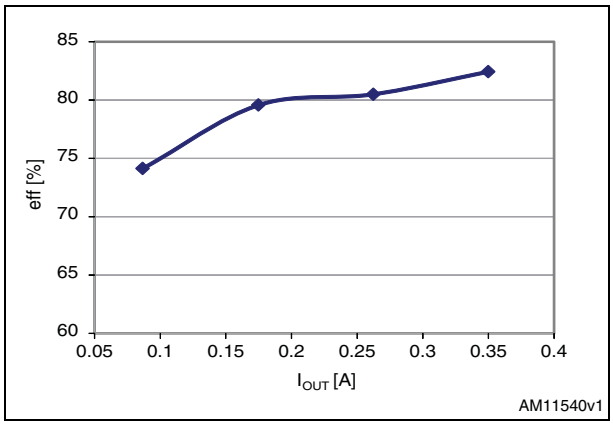


Figure 11. Input voltage averaged efficiency vs. load IC self-biased (J1 not selected)

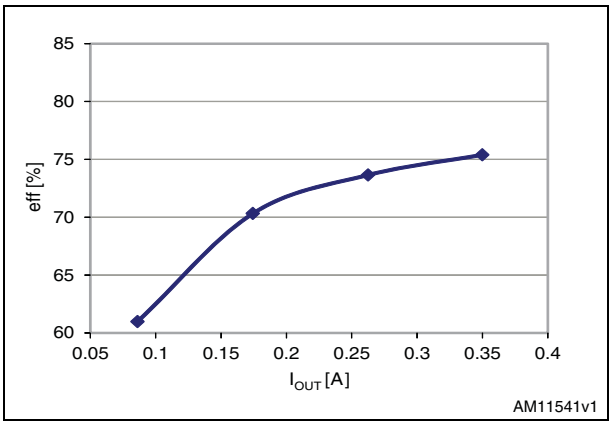


Figure 12. P_{IN} vs. V_{IN} at no load and light load: IC externally biased (J1 selected)

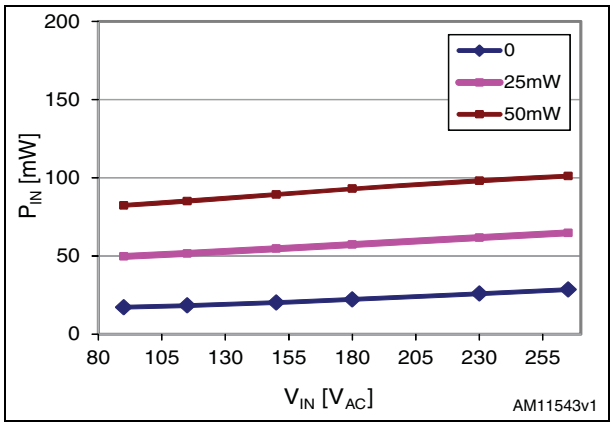


Figure 13. P_{IN} vs. V_{IN} at no load and light load: IC self-biased (J1 not selected)

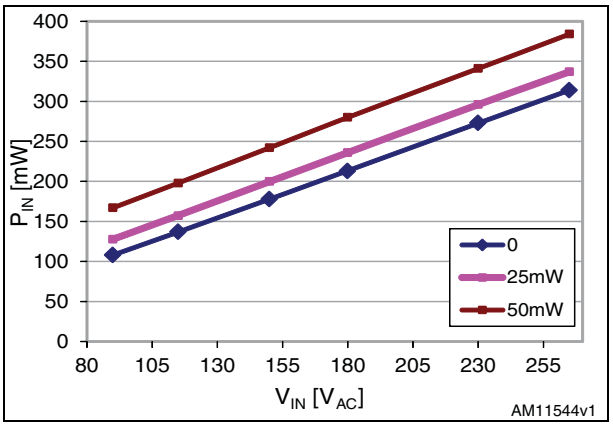


Figure 14. Efficiency at P_{IN} = 1 W: IC externally biased (J1 selected)

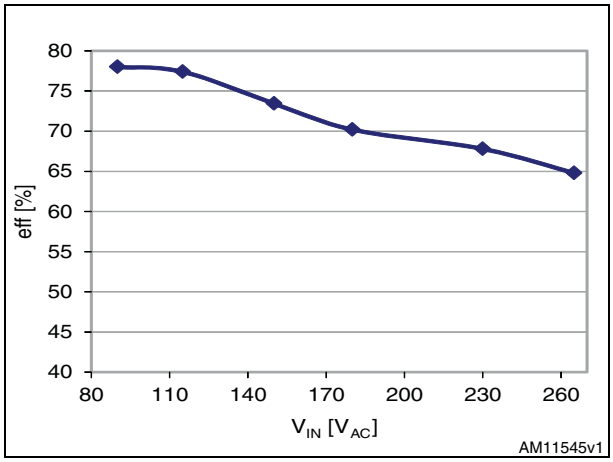


Figure 15. Efficiency at P_{IN} = 1 W: IC self-biased (J1 not selected)

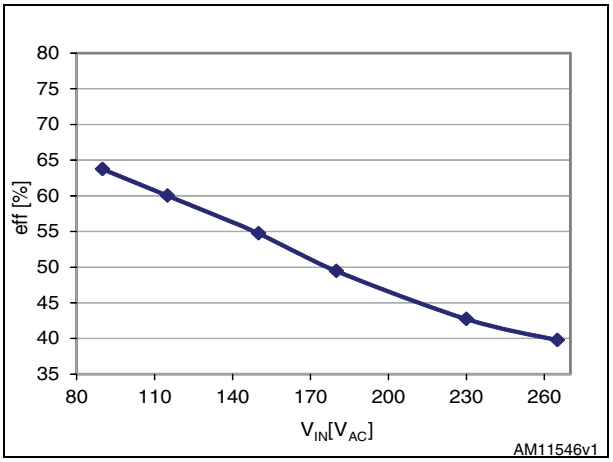


Figure 16. P_{IN} at P_{OUT} = 250 mW: IC externally biased (J1 selected)

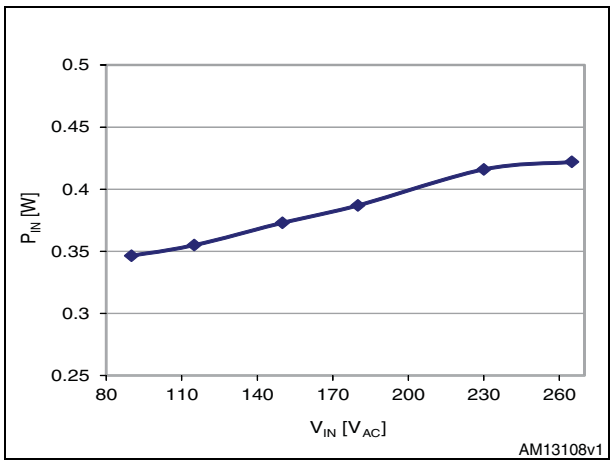
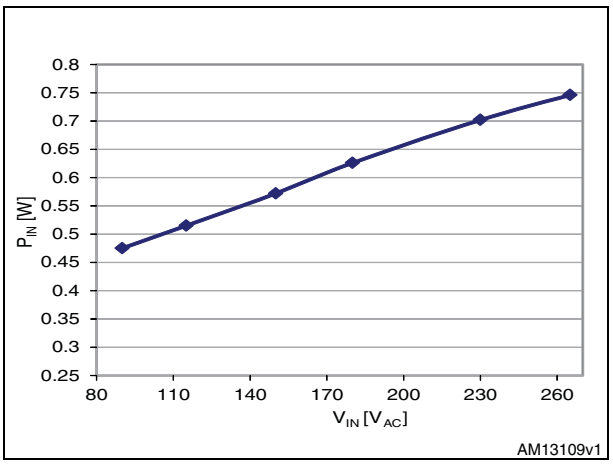


Figure 17. P_{IN} at P_{OUT} = 250 mW: IC self-biased (J1 not selected)



3 Board layout

Figure 18. Board layout - complete

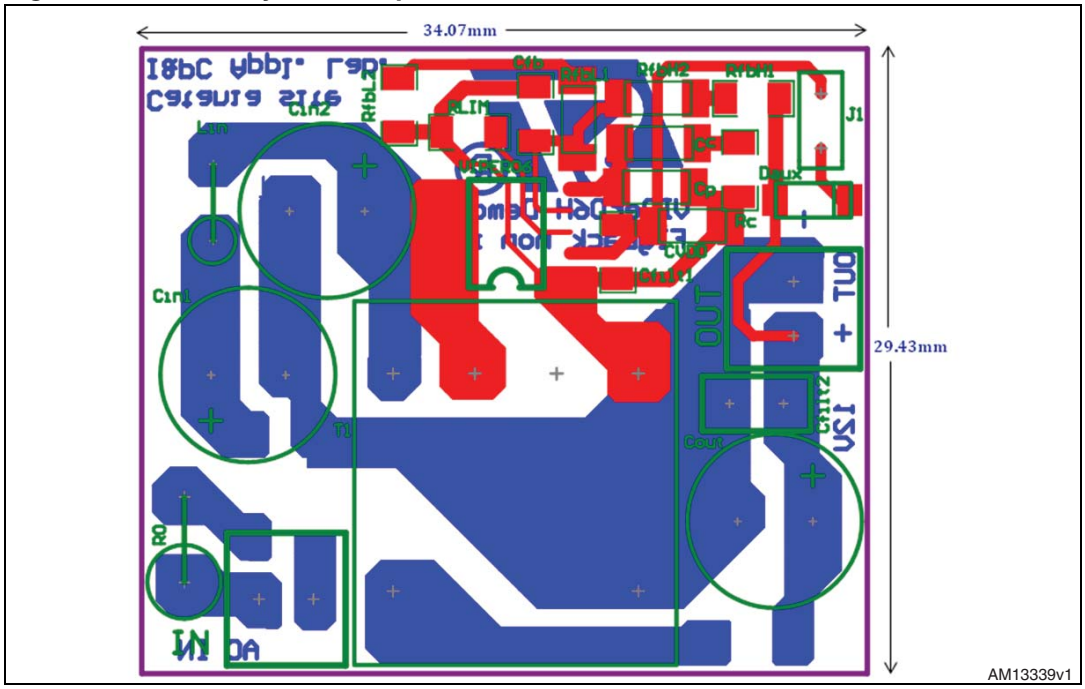


Figure 19. Board layout - top layer + top overlay

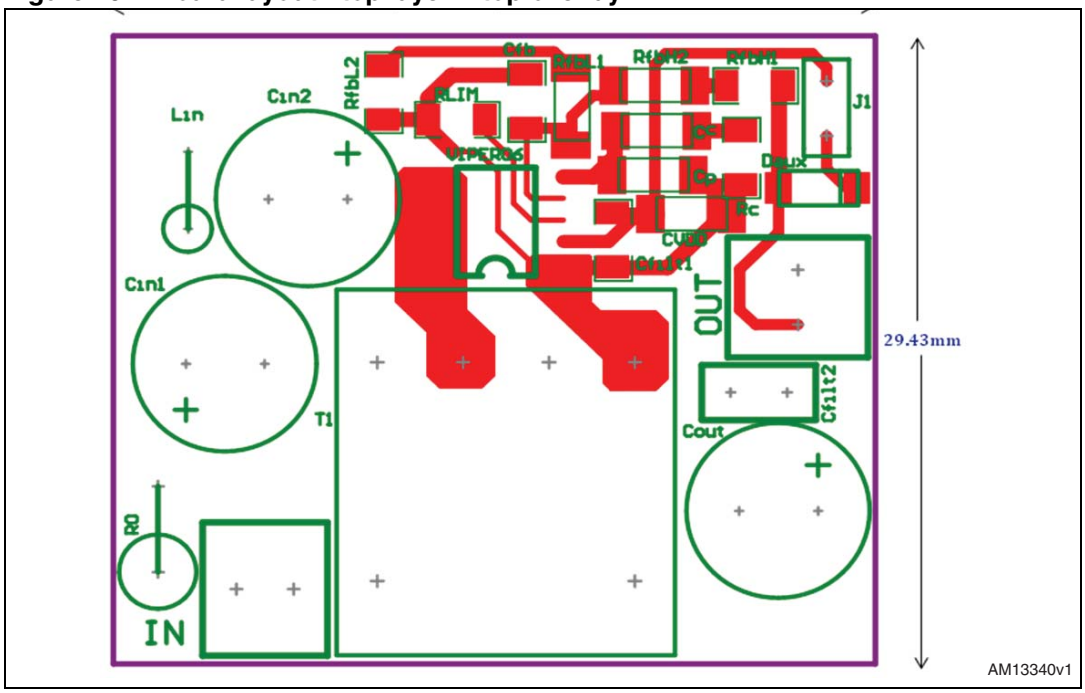
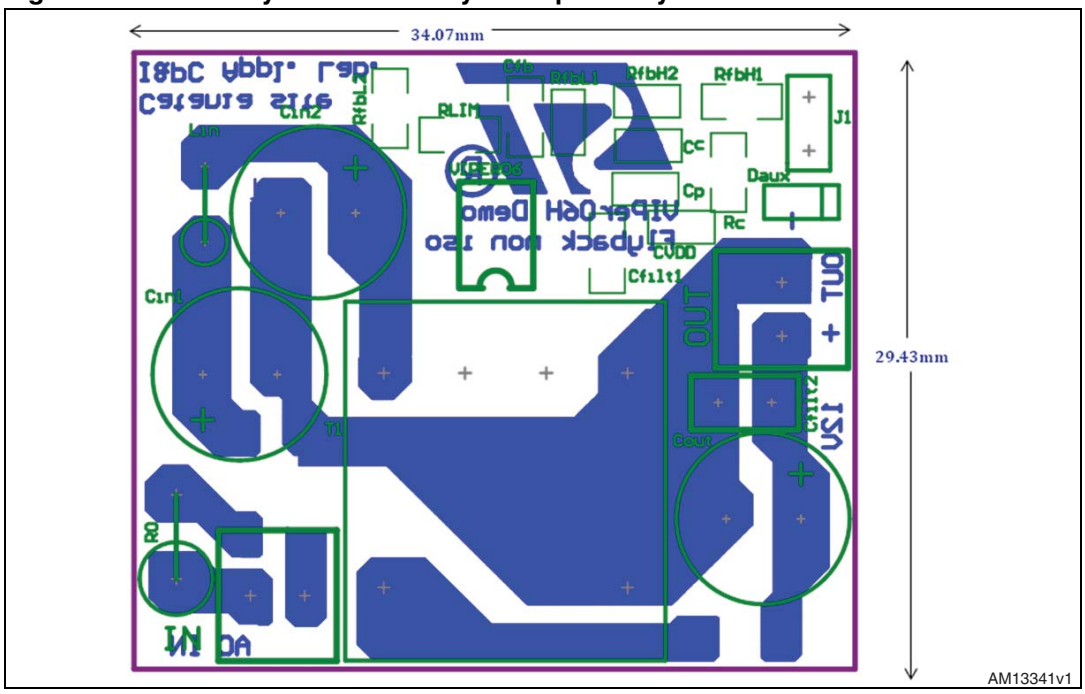


Figure 20. Board layout - bottom layer + top overlay



4 Revision history

Table 3. Document revision history

Date	Revision	Changes
10-Jan-2013	1	Initial release.

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